Page 1 of 15

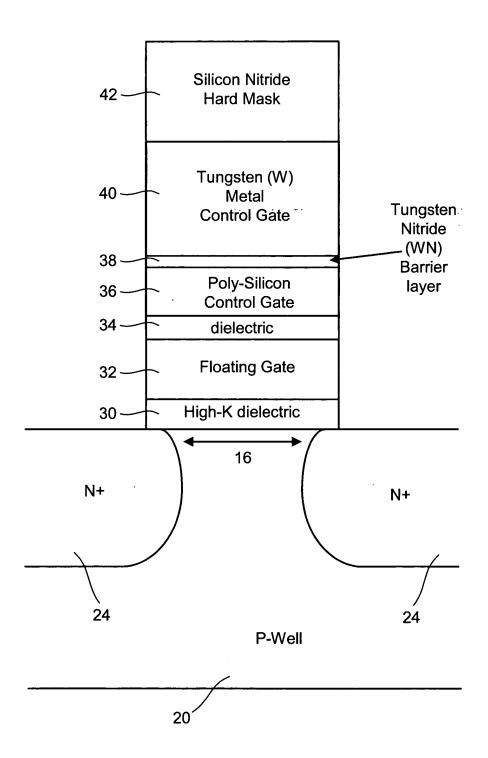
Title: Applicants: Appl. No.: Filing Date:

Express Mail No.:

NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING

Mokhlesi, et al. Unknown January 21, 2004 EL 994 763 468 US Docket No.: Atty: Phone:

Fig. 1



Page 2 of 15

Title: Applicants: Appl. No.: Filing Date:

Express Mail No.:

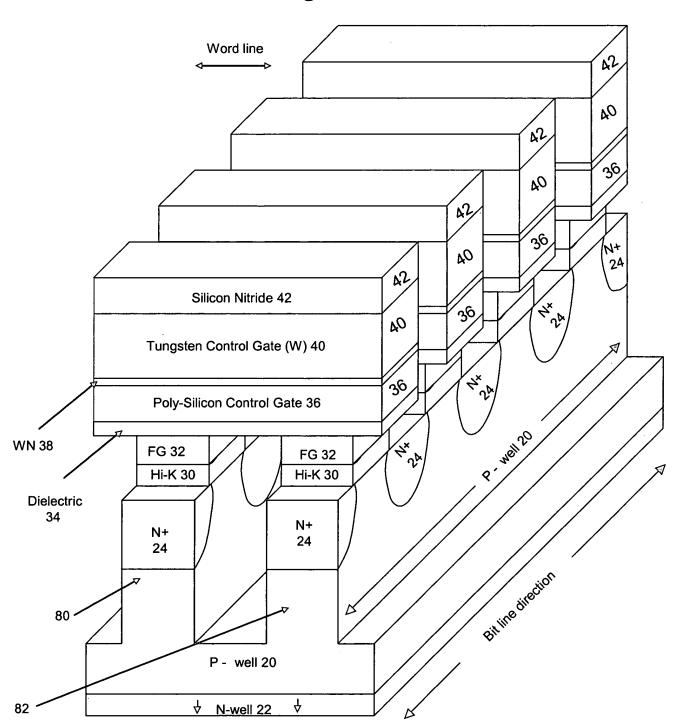
NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING Mokhlesi, et al. Docket No.: SAND-01021US0

: *.* 

Unknown January 21, 2004 EL 994 763 468 US

Atty: Phone: Burt Magen (415) 369-9660

Fig. 2



Page 3 of 15

Title: Applicants: Appl. No.: Filing Date:

Express Mail No.:

NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING Mokhlesi, et al.

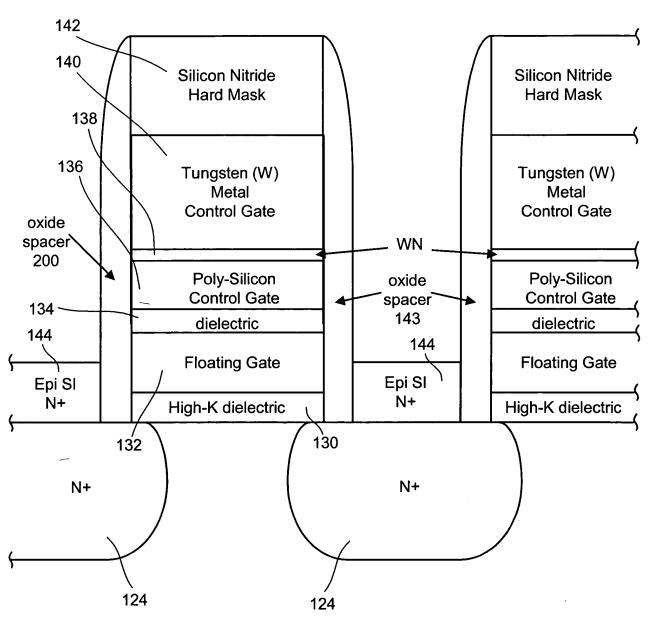
Docket No.: Atty: Phone: January 21, 2004 EL 994 763 468 US

SAND-01021US0 **Burt Magen** (415) 369-9660

Unknown

120





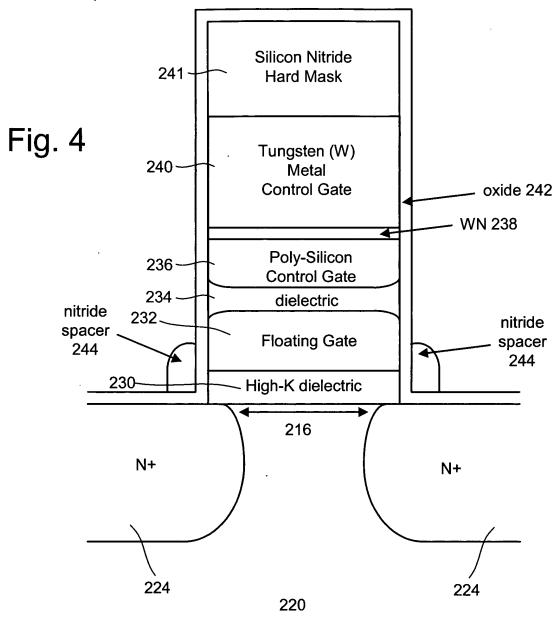
Page 4 of 15

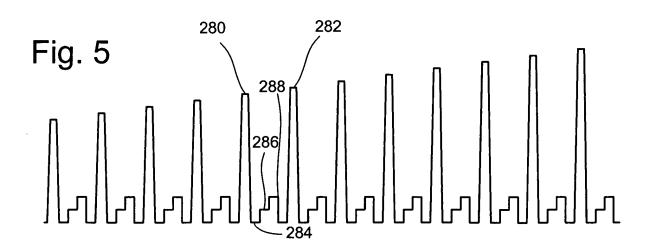
Title: Applicants: Appl. No.: NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING

Mokhlesi, et al. Unknown Docket No.: Atty: Phone: SAND-01021US0 Burt Magen

Filing Date: January 21, 2004 Express Mail No.: EL 994 763 468 US

(415) 369-9660





Page 5 of 15

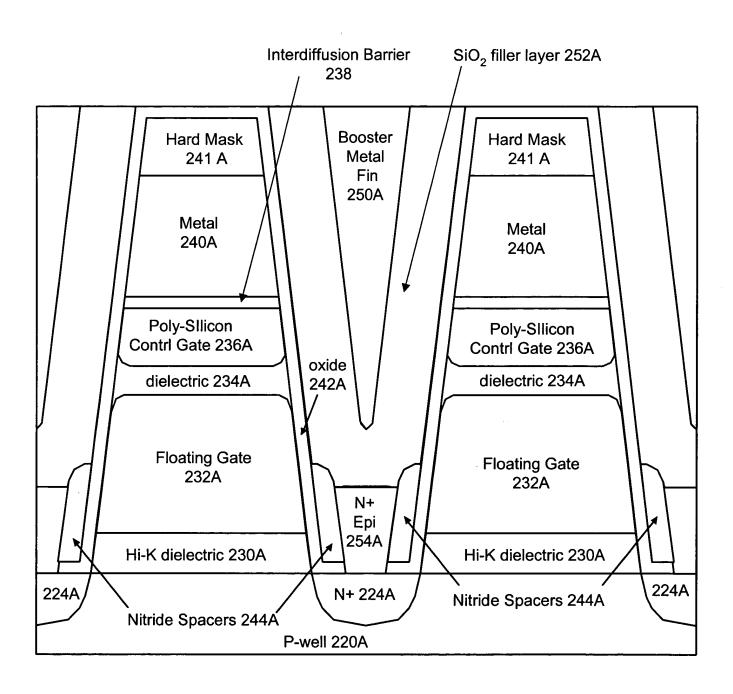
Title: Applicants: Appl. No.: Filing Date:

Express Mail No.:

NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING

Mokhlesi, et al. Unknown January 21, 2004 EL 994 763 468 US Docket No.: Atty: Phone:

Fig. 4A



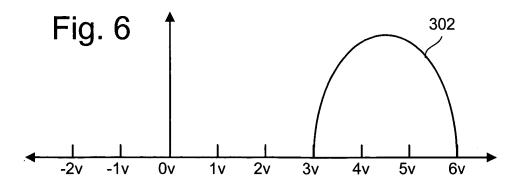
Title:

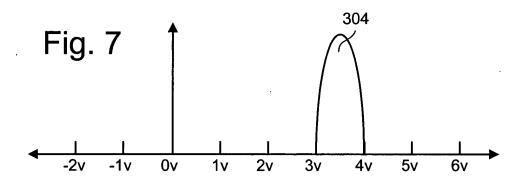
NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING

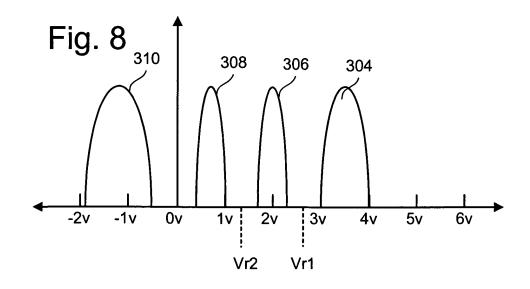
Applicants: Appl. No.: Filing Date: Express Mail No.:

Mokhlesi, et al. Unknown January 21, 2004 EL 994 763 468 US

Docket No.: Atty: Phone:







Title:
Applicants:
Appl. No.:
Filing Date:
Express Mail No.:

NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING Mokhlesi, et al. Docket No.: SAND-01021US0

 Mokhlesi, et al.
 Dock

 Unknown
 Atty:

 January 21, 2004
 Phon

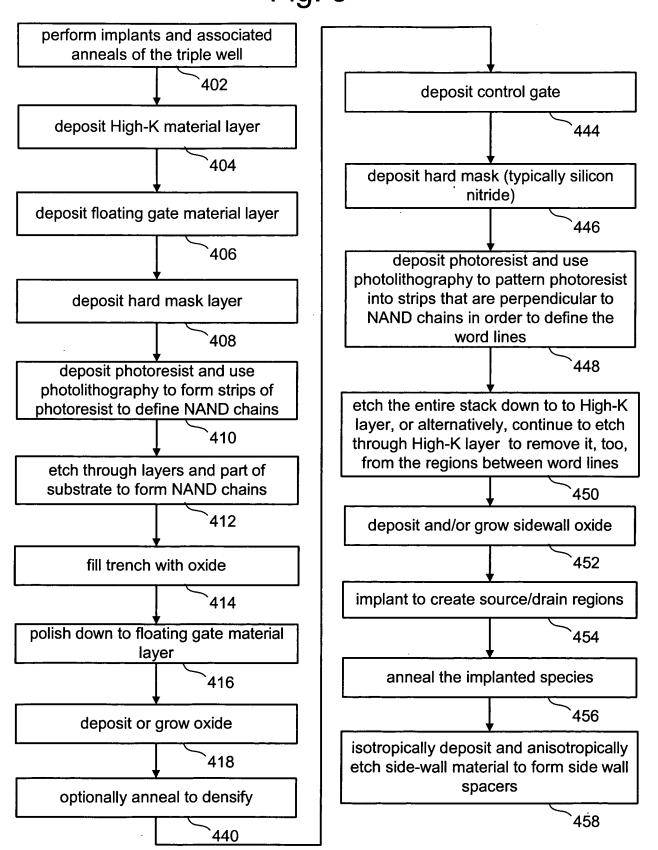
 EL 994 763 468 US

 Docket No.:
 SAND-01021US0

 Atty:
 Burt Magen

 Phone:
 (415) 369-9660

Fig. 9



Title: Applicants: Appl. No.: Filing Date:

Express Mail No.:

NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING

Mokhlesi, et al.

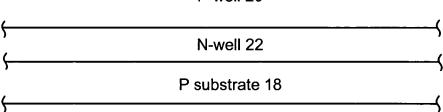
Unknown January 21, 2004 EL 994 763 468 US

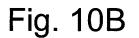
Docket No.: Atty: Phone:

SAND-01021US0 Burt Magen (415) 369-9660

Fig. 10A <sup>←</sup>











N-well 22

P substrate 18

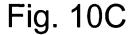
Title: Applicants: Appl. No.: Filing Date:

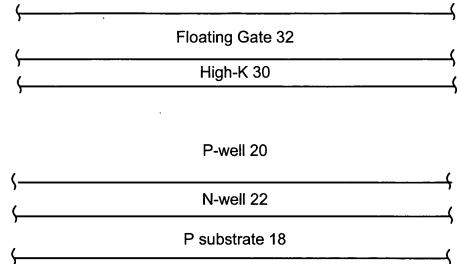
Express Mail No.:

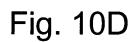
NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING

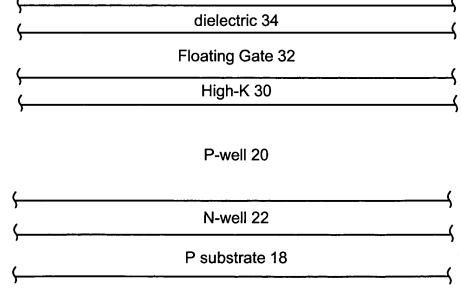
Mokhlesi, et al. Unknown January 21, 2004 EL 994 763 468 US

Docket No.: Atty: Phone:









Page 10 of 15

Title: Applicants: NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING

Appl. No.: Filing Date:

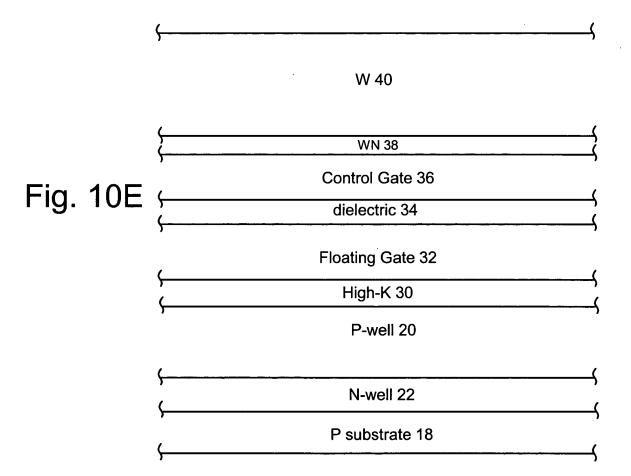
Mokhlesi, et al. Unknown

Docket No.: Atty: Phone:

SAND-01021US0 Burt Magen (415) 369-9660

Express Mail No.:

January 21, 2004 EL 994 763 468 US



Page 11 of 15

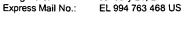
Title: Applicants: NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING Mokhlesi, et al. Docket No.: SAND-01021US0

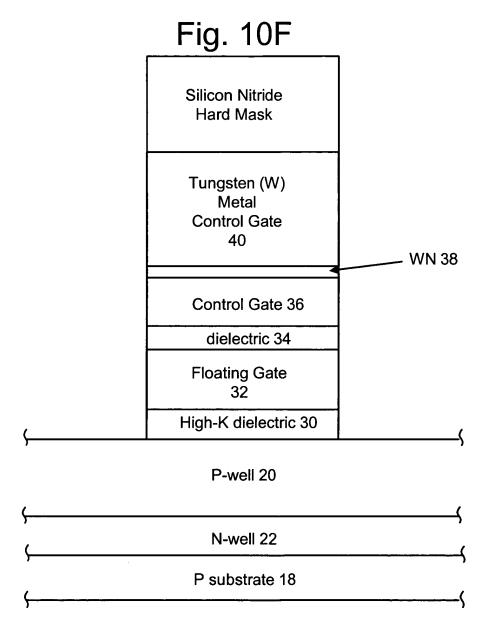
Appl. No.: Filing Date:

Unknown January 21, 2004 EL 994 763 468 US

Atty: Phone:

Burt Magen (415) 369-9660





Page 12 of 15

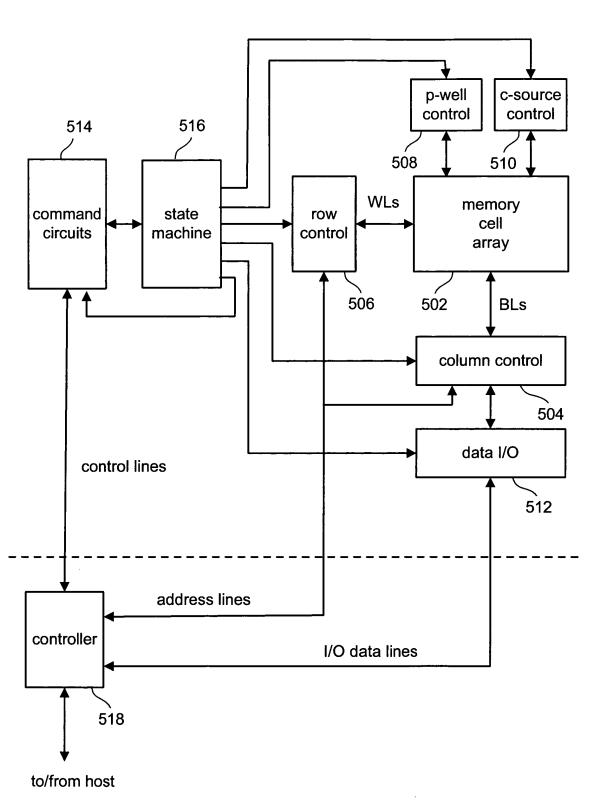
Title: Applicants: Appl. No.: Filing Date:

Express Mail No.:

NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING Mokhlesi, et al. Docket No.: SAND-01021US0

Unknown January 21, 2004 EL 994 763 468 US Atty: Phone: Burt Magen (415) 369-9660

Fig. 11



Page 13 of 15

Title: Applicants: Appl. No.: Filing Date:

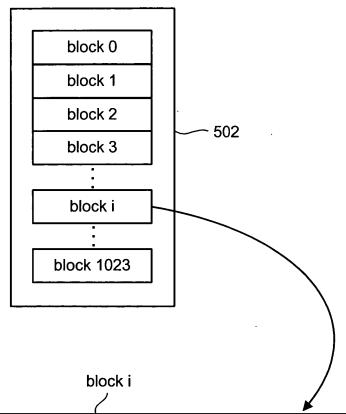
Express Mail No.:

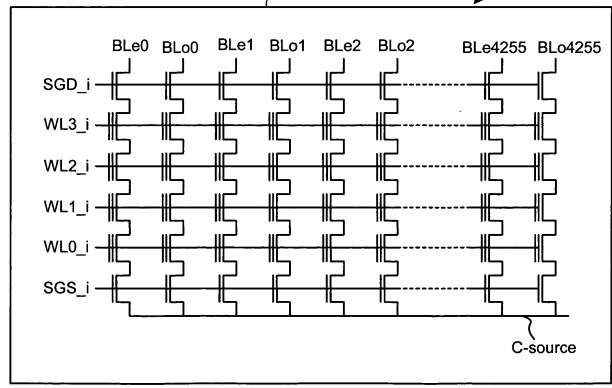
NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING Mokhlesi, et al. Docket No.: SAND-01021US0

Mokhlesi, et al. Unknown January 21, 2004 EL 994 763 468 US

Atty: Phone:

Fig. 12



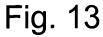


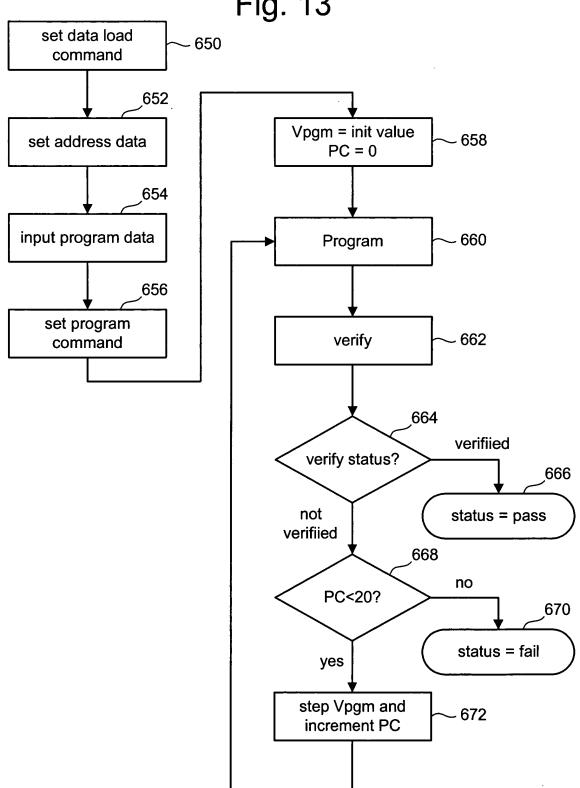
Title: Applicants: Appl. No.: Filing Date:

Express Mail No.:

NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING

Mokhlesi, et al. Unknown January 21, 2004 EL 994 763 468 US Docket No.: Atty: Phone:





Page 15 of 15

Title: NON-VOLAT

NON-VOLATILE MEMORY CELL USING HIGH-K MATERIAL AND INTER-GATE PROGRAMMING

Applicants: Appl. No.: Filing Date:

Express Mail No.:

Mokhlesi, et al. Unknown January 21, 2004 EL 994 763 468 US Docket No.: Atty: Phone:

Fig. 14

